

Features

- Advanced high cell density Trench technology
- Super Low Gate Charge
- Excellent CdV/dt effect decline
- 100% EAS Guaranteed
- Green Device Available

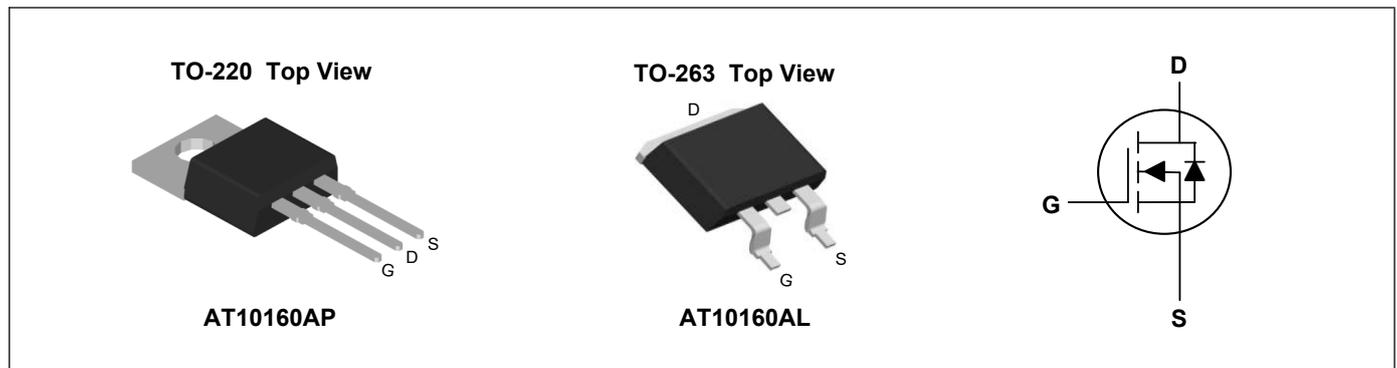
Applications

- High Frequency Point-of-Load, Synchronous Buck Converter
- Networking DC-DC Power System
- Load Switch

Product Summary



V_{DS}	100	V
I_D	160	A
$R_{DS(ON)}$ (at $V_{GS}=10V$)	3.3	m Ω



Absolute Maximum Ratings($T_C=25^\circ C$, unless otherwise noted)

Parameter	Symbol	Rating	Units
Drain-Source Voltage	V_{DS}	100	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current ¹	I_D	160	A
Continuous Drain Current ¹	$I_D@T_C=100^\circ C$	120	A
Pulsed Drain Current ²	I_{DM}	640	A
Single Pulse Avalanche Energy ³	EAS	1345	mJ
Total Power Dissipation ⁴	P_D	245	W
Storage Temperature Range	T_{STG}	-55 to 175	$^\circ C$
Operating Junction Temperature Range	T_J	-55 to 175	$^\circ C$

Thermal Characteristics

Parameter	Symbol	Typ	Max	Unit
Thermal Resistance Junction-Case ¹	$R_{\theta JC}$	---	0.61	$^\circ C/W$

Electrical Characteristics (T_J=25°C, unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	100	---	---	V
Static Drain-Source On-Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =80A TO-220	---	2.9	3.3	mΩ
		V _{GS} =10V, I _D =80A TO-263	---	2.7	3.3	mΩ
Gate Threshold Voltage	V _{GS(th)}	V _{GS} =V _{DS} , I _D =250uA	2	3	4	V
Drain-Source Leakage Current	I _{DSS}	V _{DS} =100V, V _{GS} =0V, T _J =25°C	---	---	1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V	---	---	±100	nA
Forward Transconductance	g _{fs}	V _{DS} =5V, I _D =80A	85	---	---	S
Total Gate Charge	Q _g	V _{DS} =50V, V _{GS} =10V, I _D =80A	---	127	---	nC
Gate-Source Charge	Q _{gs}		---	41	---	
Gate-Drain Charge	Q _{gd}		---	35	---	
Turn-On Delay Time	T _{d(on)}	V _{DD} =50V, R _G =1.6Ω, V _{GS} =10V, I _D =80A	---	25	---	ns
Rise Time	T _r		---	15	---	
Turn-Off Delay Time	T _{d(off)}		---	52	---	
Fall Time	T _f		---	17	---	
Input Capacitance	C _{iss}	V _{DS} =50V, V _{GS} =0V, f=1MHz	---	7810	---	pF
Output Capacitance	C _{oss}		---	887	---	
Reverse Transfer Capacitance	C _{rss}		---	30	---	

Drain-Source Diode Characteristics

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Continuous Source Current ²	I _S		---	---	160	A
Diode Forward Voltage ¹	V _{SD}	V _{GS} =0V, I _S =80A, T _J =25°C	---	---	1.2	V
Reverse Recovery Time	t _{rr}	I _F =80A, di/dt=100A/μs, T _J =25°C	---	74	---	nS
Reverse Recovery Charge	Q _{rr}		---	164	---	nC

Note:

- The data tested by surface mounted on a 1 inch² FR-4 board with 20Z copper.
- The data tested by pulsed, pulse width ≤ 300us, duty cycle ≤ 2%
- The EAS data shows Max. rating. The test condition is V_{DD}=50V, V_{GS}=10V, L=0.5mH
- The power dissipation is limited by 175°C junction temperature

Typical Characteristics

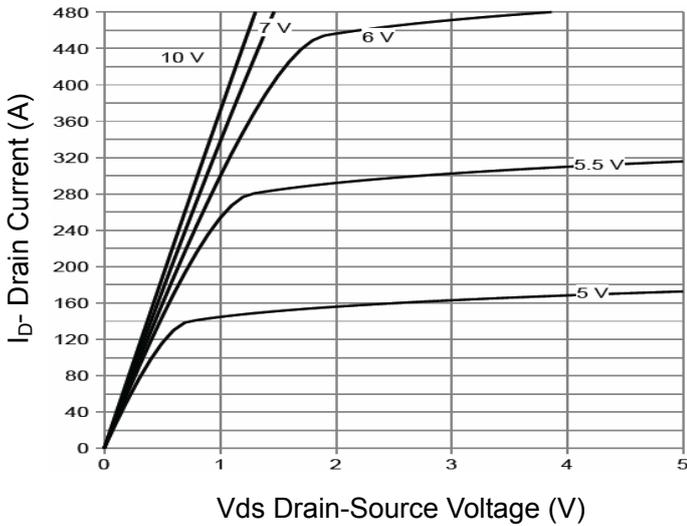


Figure 1 Output Characteristics

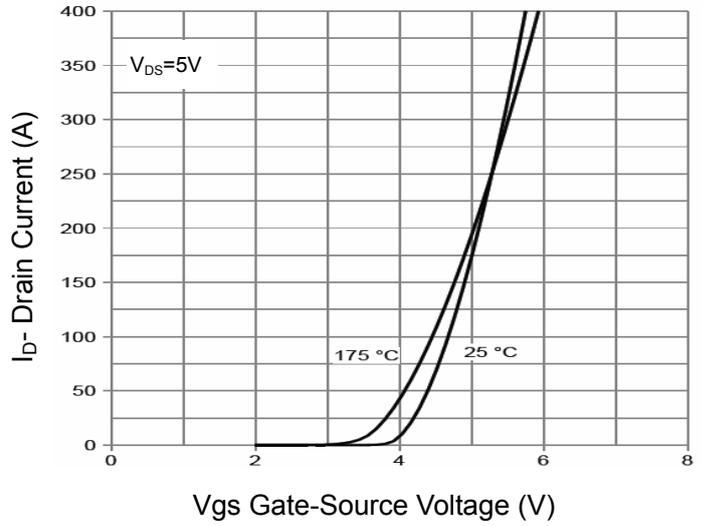


Figure 2 Transfer Characteristics

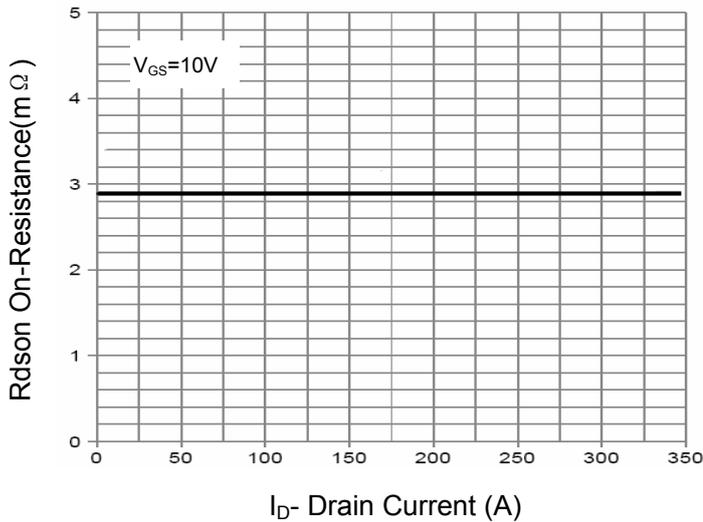


Figure 3 Rdson- Drain Current

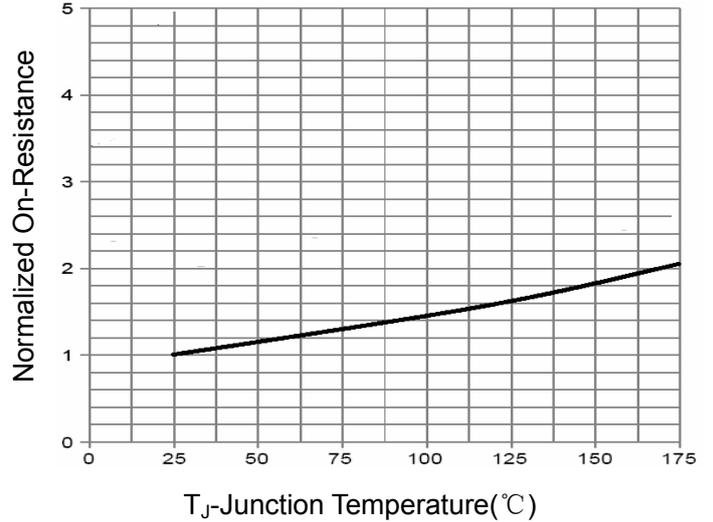


Figure 4 Rdson-Junction Temperature

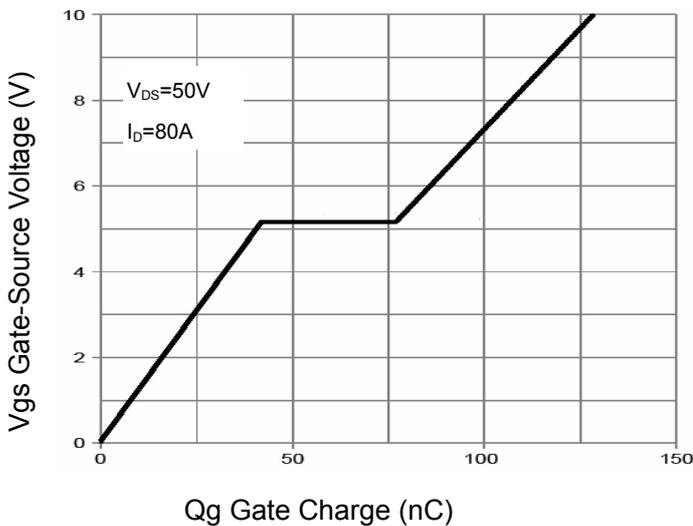


Figure 5 Gate Charge

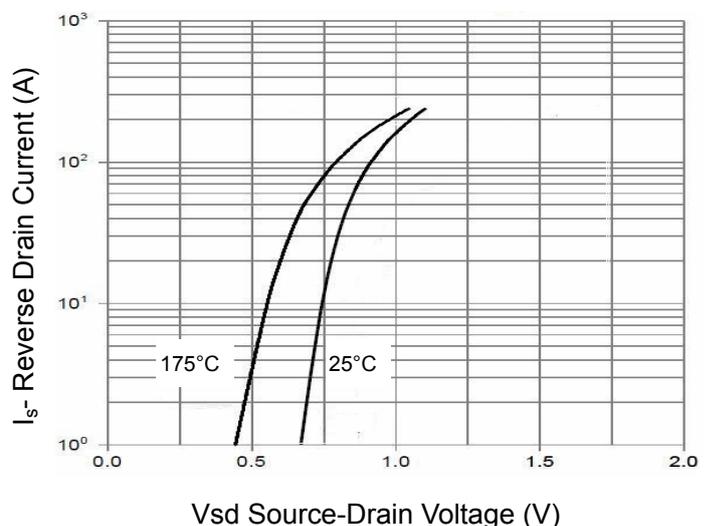


Figure 6 Source- Drain Diode Forward

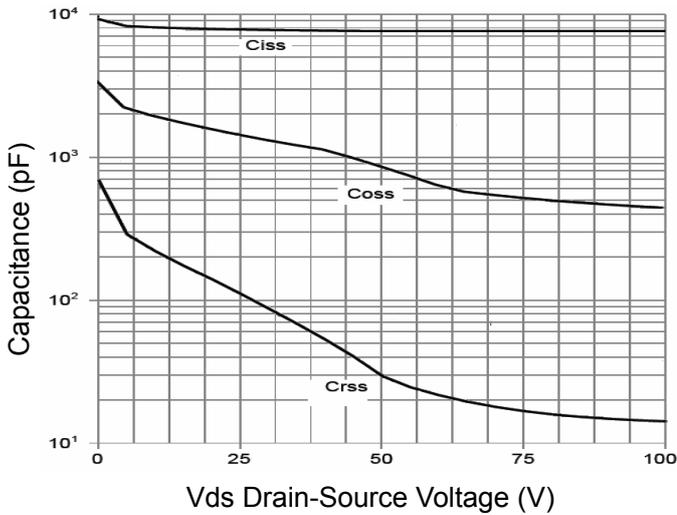


Figure 7 Capacitance vs Vds

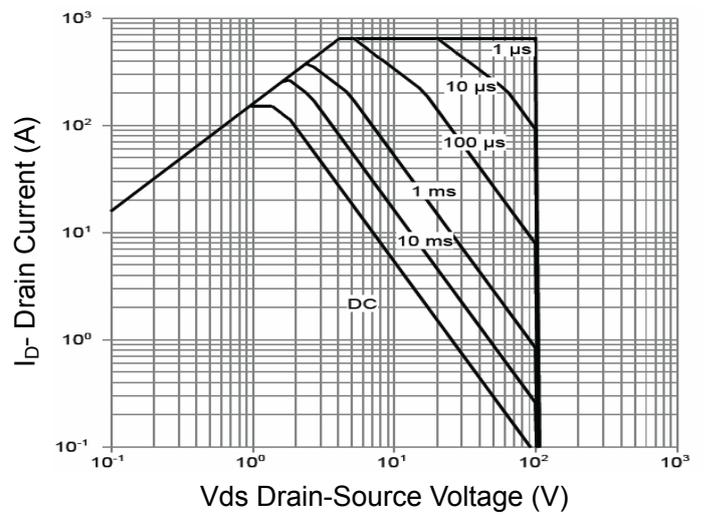


Figure 8 Safe Operation Area

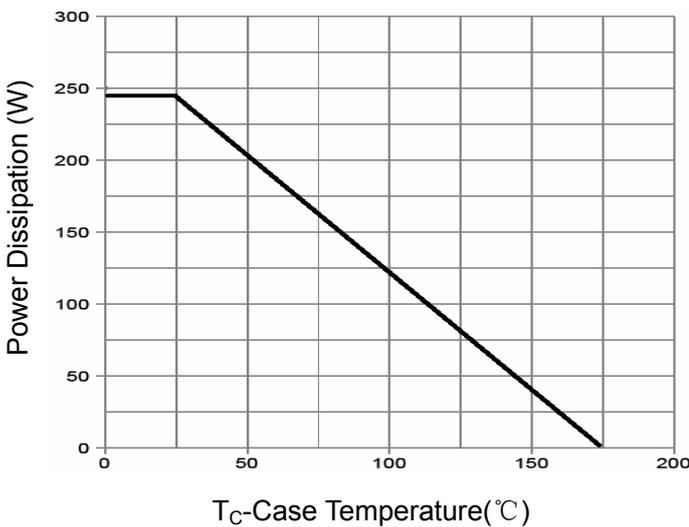


Figure 9 Power De-rating

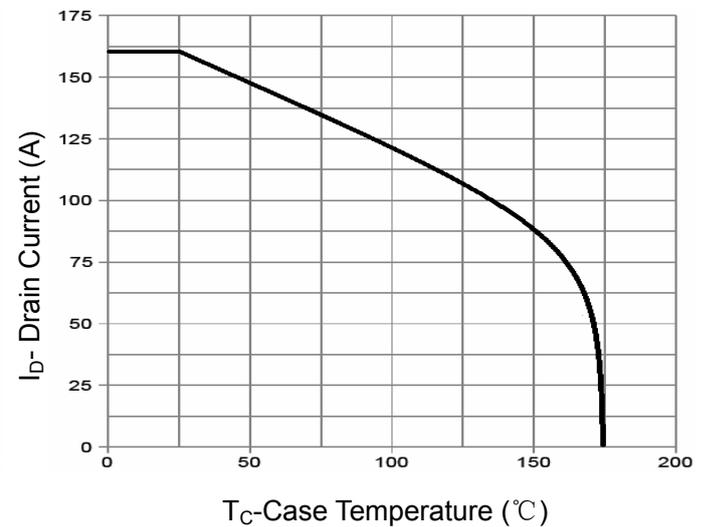


Figure 10 Current De-rating

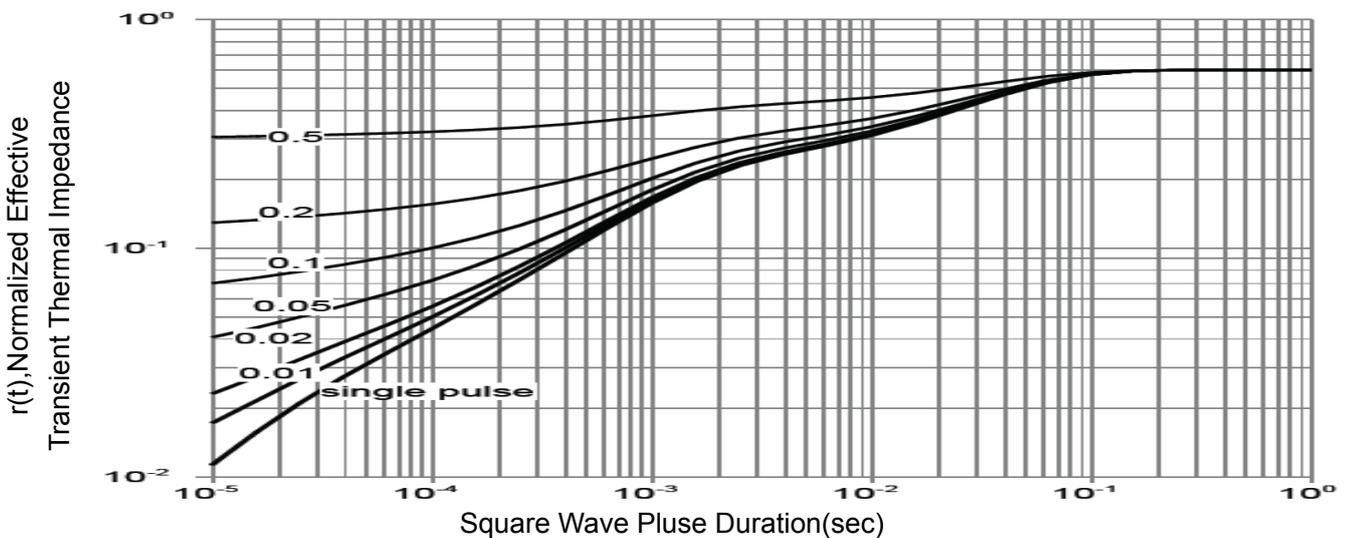
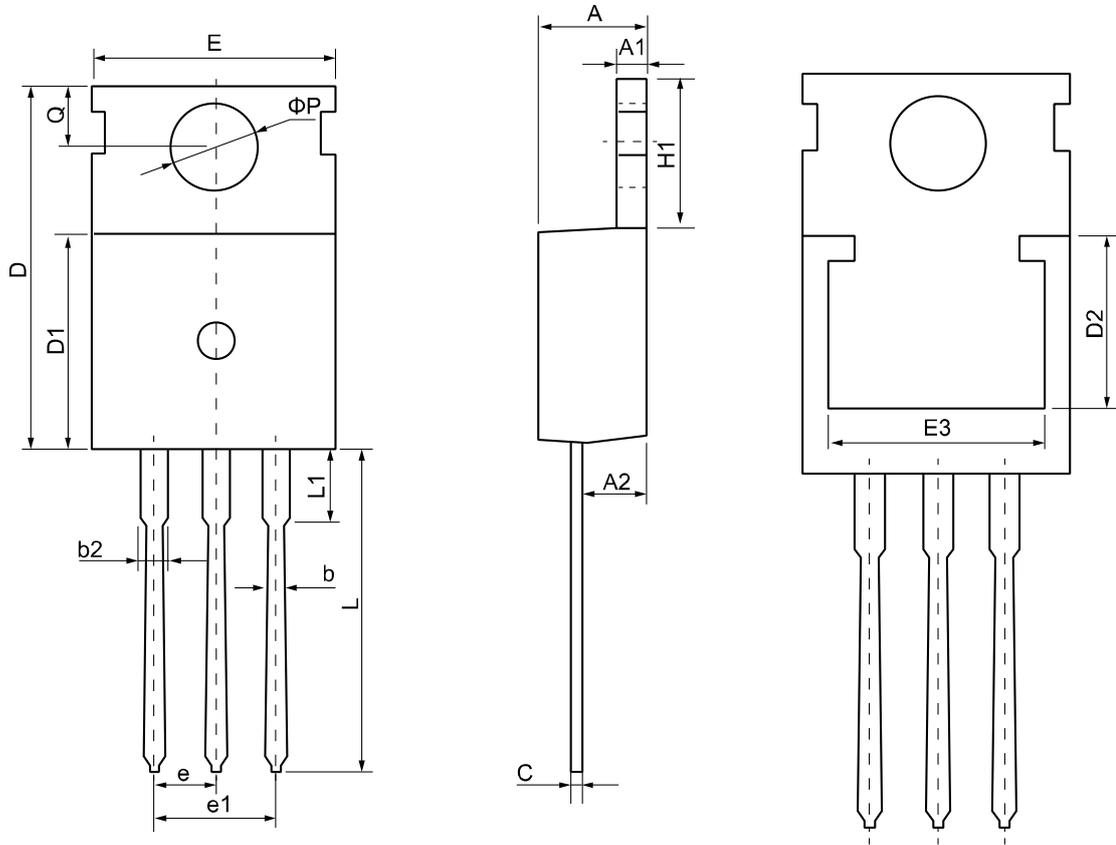


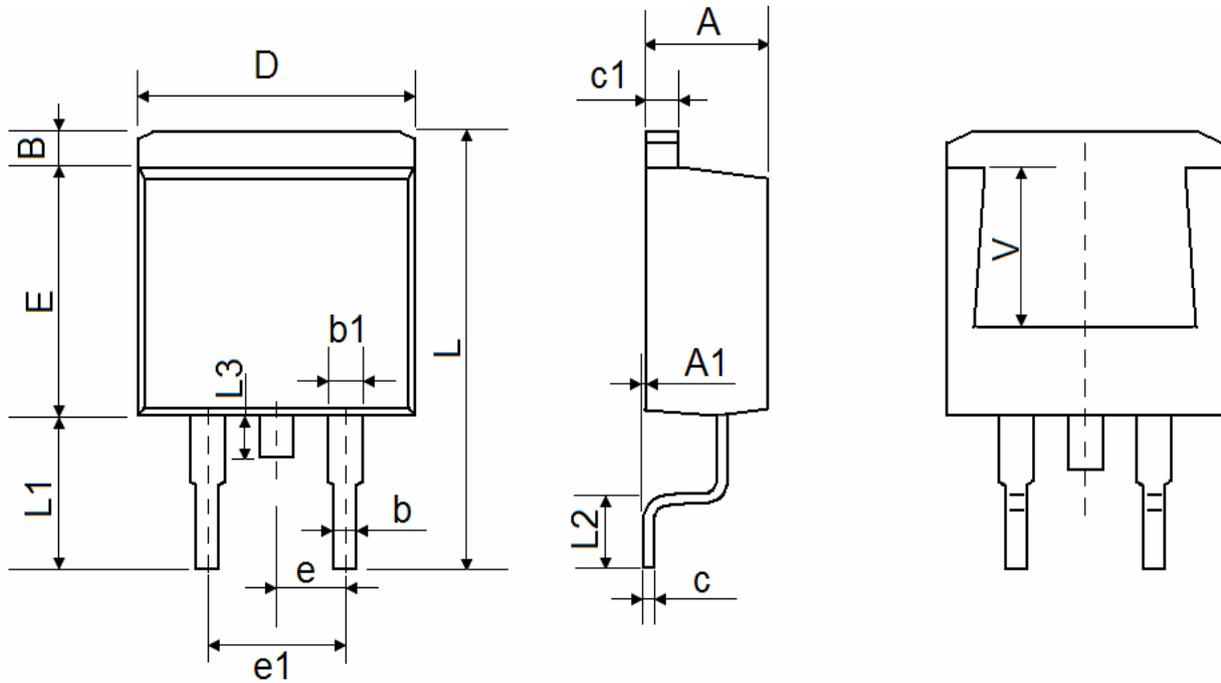
Figure 11 Normalized Maximum Transient Thermal Impedance

TO-220 Package Outline Dimensions



Symbol	Dimensions (unit:mm)			Symbol	Dimensions (unit:mm)		
	Min	Typ	Max		Min	Typ	Max
A	4.30	4.55	4.75	E	9.65	10.00	10.25
A1	1.15	1.30	1.45	E3	7.00	--	--
A2	2.20	2.40	2.60	e	2.54 BSC		
b	0.70	0.80	0.95	e1	5.08 BSC		
b2	1.17	1.27	1.47	H1	6.30	6.50	6.80
c	0.40	0.50	0.65	L	12.70	13.50	14.10
D	15.30	15.60	15.90	L1	--	3.20	3.95
D1	8.90	9.10	9.35	φP	3.40	3.60	3.80
D2	5.50	--	--	Q	2.60	2.80	3.00

TO-263 Package Outline Dimensions



Symbol	Dimensions (unit:mm)			Symbol	Dimensions (unit:mm)		
	Min	Typ	Max		Min	Typ	Max
A	4.40	4.55	4.70	A1	0.00	0.07	0.15
B	1.00	1.20	1.40	b	0.65	0.80	0.95
b1	1.10	1.15	1.37	c	0.30	0.40	0.53
c1	1.10	1.25	1.37	D	9.80	10.00	10.40
E	8.50	8.80	9.20	e	2.54 REF		
e1	4.90	5.10	5.40	L	14.80	15.20	15.70
L1	5.00	5.25	5.60	L2	2.05	2.45	2.80
L3	1.20	1.50	1.80	V	5.60 REF		